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ON Semiconductor®

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www.onsemi.com

Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

July 2017

ON Semiconductor®

FFPF20UA60DN

20 A, 600 V, Ultrafast II Dual Diode

Features

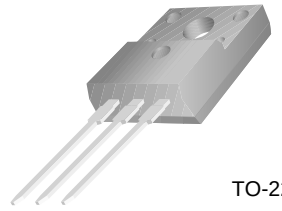
- Ultrafast Recovery t_{rr} = 120 ns (@ I_F = 10 A)
- Max Forward Voltage, V_F = 2.3 V (@ T_C = 25°C)
- 600 V Reverse Voltage and High Reliability
- Avalanche Energy Rated
- RoHS Compliant

Applications

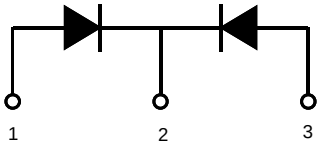
- Boost Diode in PFC and SMPS

Description

The FFPF20UA60DN is an ultrafast ll dual diode with low forward voltage drop and rugged UIS capability. This device is intended for use as freewheeling and clamping diodes in a variety of switching power supplies and other power switching applications. It is specially suited for use in switching power supplies and industrial applications as welder and UPS application.



TO-220F



1. Anode 2. Cathode 3. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Rating	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	600	V
V_{RWM}	Working Peak Reverse Voltage	600	V
V_R	DC Blocking Voltage	600	V
$I_{F(AV)}$	Average Rectified Forward Current @ T_C = 25°C	10	A
I_{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	50	A
T_J, T_{STG}	Operating and Storage Temperature Range	-65 to +175	°C

Thermal Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Max.	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	6.3	°C/W

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FFPF20UA60DN	FFPF20UA60DN	TO-220F	Tube	N/A	N/A	50

Electrical Characteristics $T_C = 25^oC$ unless otherwise noted

Symbol	Parameter		Min.	Typ.	Max.	Unit
V_{FM}1	I_F = 10 A I_F = 10 A	$T_C = 25^oC$ $T_C = 125^oC$	- -	1.8 1.7	2.3 2.2	V
I_{RM}1	V_R = 600 V V_R = 600 V	$T_C = 25^oC$ $T_C = 125^oC$	- -	- -	100 500	μA
t_{rr} I_{rr} Q_{rr}	I_F = 10 A, di_F/dt = 200 A/μs	$T_C = 25^oC$		74 6 213	120 10 600	ns A nC
W_{AVL}	Avalanche Energy (L = 40 mH)		10	-	-	mJ

Notes:
1: Pulse: Test Pulse width = 300μs, Duty Cycle = 2%

Test Circuit and Waveforms

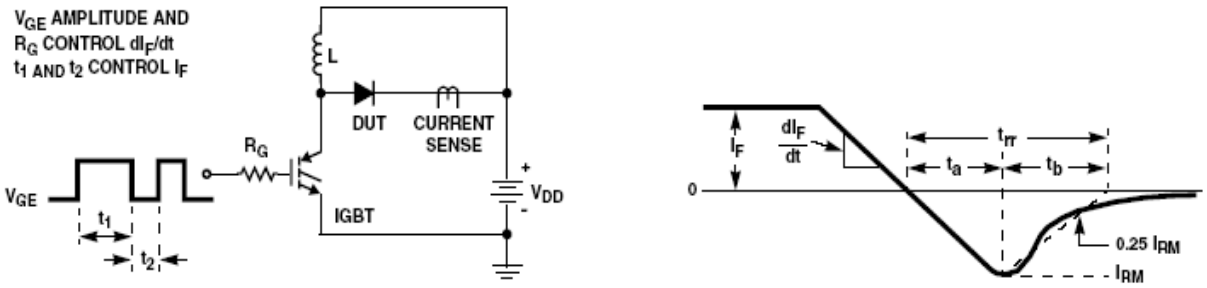


Figure 1. Diode Reverse Recovery Test Circuit & Waveform

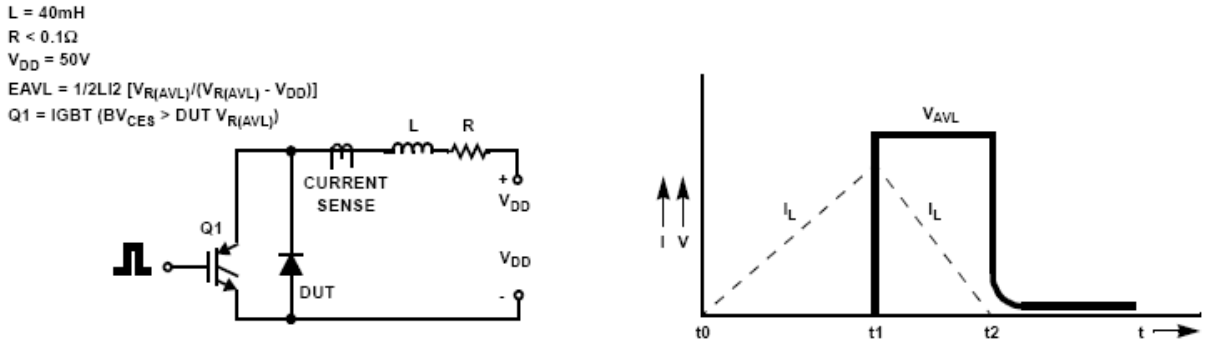


Figure 2. Unclamped Inductive Switching Test Circuit & Waveform

Typical Performance Characteristics

Figure 3. Typical Forward Voltage Drop vs. Forward Current

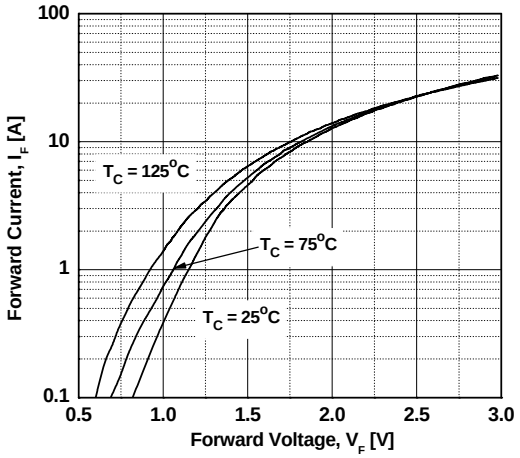


Figure 4. Typical Reverse Current vs. Reverse Voltage

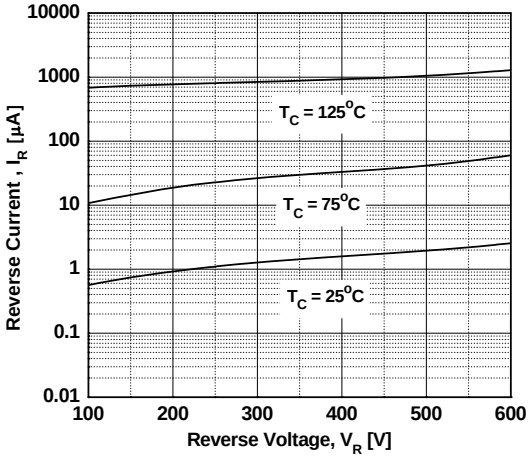


Figure 5. Typical Junction Capacitance

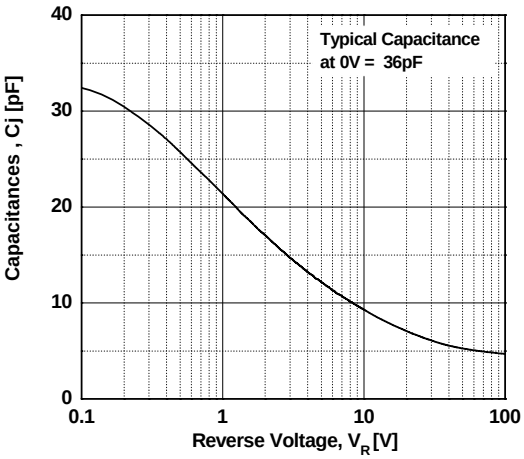


Figure 6. Typical Reverse Recovery Time vs. di_F/dt

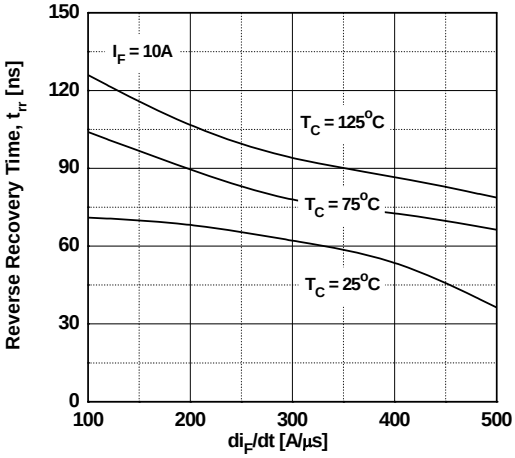


Figure 7. Typical Reverse Recovery Current vs. di_F/dt

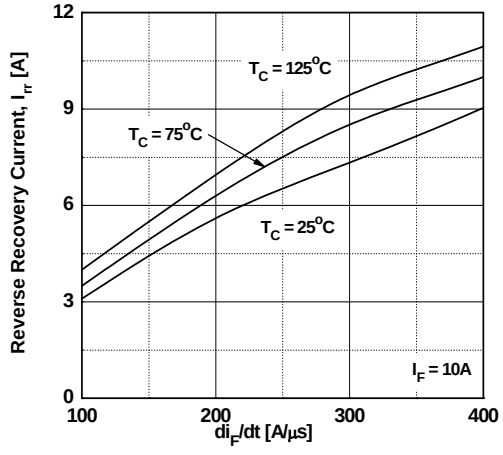
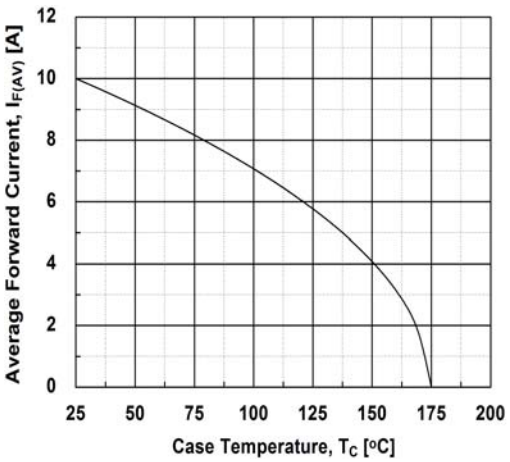
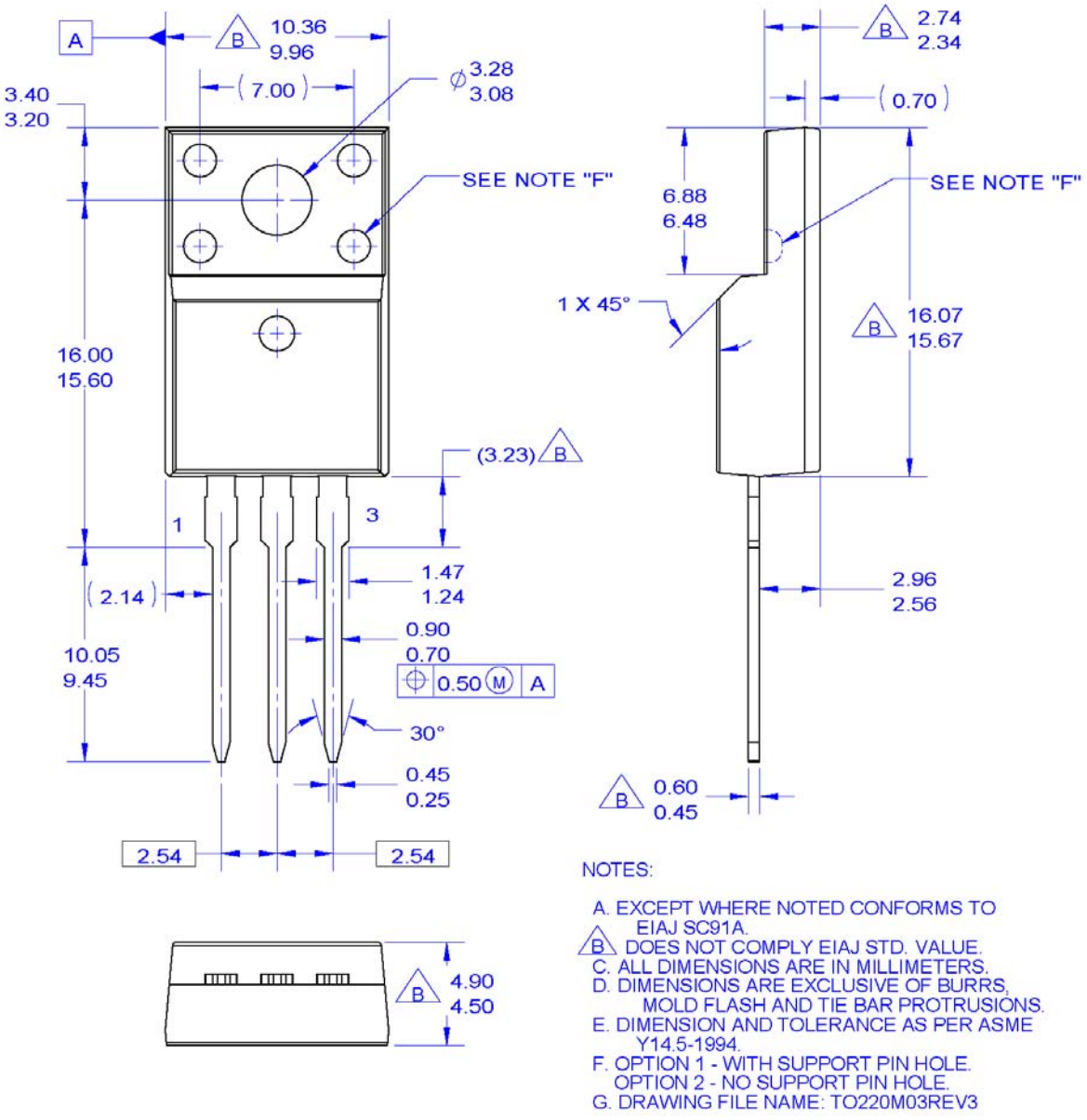


Figure 8. Forward Current Derating Curve



Package Dimensions



NOTES:

A. EXCEPT WHERE NOTED CONFORMS TO EIAJ SC91A.
B. DOES NOT COMPLY EIAJ STD. VALUE.
C. ALL DIMENSIONS ARE IN MILLIMETERS.
D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
E. DIMENSION AND TOLERANCE AS PER ASME Y14.5-1994.
F. OPTION 1 - WITH SUPPORT PIN HOLE.
OPTION 2 - NO SUPPORT PIN HOLE.
G. DRAWING FILE NAME: TO220M03REV3

PUBLICATION ORDERING INFORMATION

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Phone: 303−675−2175 or 800−344−3860 Toll Free USA/Canada
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